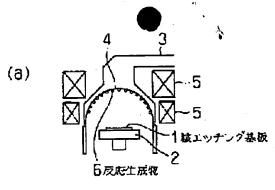
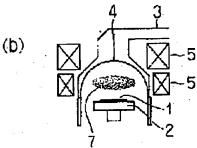
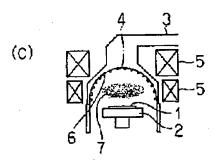


Patent Details:
Patent No Kind Lan Pg Main IPC Filing notes
JP 8017804 A 7 H01L-021/3065
TO 2207063 B2 7 H01L-021/3065 Previous Publ. patent JP 8017804 Plasma discharge pretreatment with fluorine gp. gas is achieved for each substrate or plasma discharge post-treatment by fluorine gp. gas is achieved using single electrode static chuck. ADVANTAGE -The process has improved stability and uniformity. Dwg.1/3

Priority Applications (No Type Date): JP 94152475 A 19940704







Title Terms: PLASMA; ETCH; IMPROVE; STABILISED; FLUORINE; GROUP; GAS; REMOVE; SURFACE; OXIDE; FILM Derwent Class: L03; M14; U11 International Patent Class (Main): H01L-021/3065 International Patent Class (Additional): C23F-004/00

File Segment: CPI: EPI
Manual Codes (CPI/A-N): L04-C07D; M14-A04
Manual Codes (EPI/S-X): U11-C07A1

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